

Room temperature stable single-photon source

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Abstract. We report on the realization of a stable solid state room temperature source for single photons. It is based on the fluorescence of a single nitrogen-vacancy (NV) color center in a diamond nanocrystal. Antibunching has been observed in the fluorescence light under both continuous and pulsed excitation. Our source delivers $2 \times 10^4 \text{ s}^{-1}$ single-photon pulses at an excitation repetition rate of 10 MHz. The number of two-photon pulses is reduced by a factor of five compared to strongly attenuated coherent sources.

PACS. 42.50.Dv Nonclassical field states; squeezed, antibunched, and sub-Poissonian states; operational definitions of the phase of the field; phase measurements – 03.67.-a Quantum information – 78.67.-n Optical properties of nanoscale materials and structures

1 Introduction

The security of quantum cryptography is based on the fact that quantum mechanics does not allow one to duplicate an unknown state of a single quantum system (for a review see [1]). This property is referred to as the no-cloning theorem. After the pioneering experiment of the group of Bennett and Brassard [2], several quantum key distribution set-ups using attenuated laser pulses have been demonstrated (see for example Refs. [1, 3]). In these implementations, single photons are approximated by strongly attenuated coherent pulses so that the average number of photons per pulse is $p_1 \approx 0.1$. In this case, the probability of having two photons in a pulse is approximately $p_1^2/2$ [4]. Two-photon pulses are a potential information leakage source [5]. Indeed, an eavesdropper could tap on the communication between the sender (Alice) and the receiver (Bob), by keeping one of the two photons and sending the other one to Bob. The eavesdropper can then measure the state of the photon once Alice and Bob have revealed their measurement basis. With attenuated coherent pulses, the only way to reduce the probability of having two photons in a pulse is to lower p_1 and thereby decreasing the transmission rate. Our aim is to realize an efficient single-photon source that would have a vanishing two photon probability for a non vanishing transmission rate.

Single photons on demand can be produced by pulsed excitation of a single dipole [6, 7]. The principle is that a single emitting dipole has to undergo a full excitation-

emission-reexcitation cycle before emitting a second photon. For a sufficiently short and intense excitation pulse, a single dipole emits one and only one photon [7].

Several solid state sources, like single organic molecules [8–13], self-assembled semiconductor quantum dots [14–16], or semiconductor nanocrystals [17] have been presented lately as potential candidates. However, the ideal candidate should be photostable, work at room temperature and be easy to manipulate. Single nitrogen-vacancy (NV) color centers in bulk diamond [18] have recently been shown to exhibit strong antibunching at room temperature [19–21]. They are intrinsically photostable and are believed to have a unity quantum efficiency [22]. The high refractive index of diamond leads however to a small collection efficiency owing to total internal reflection and spherical aberrations. Also, the signal to background ratio is limited by the light emitted from the surrounding diamond crystal. One can also point out that bulk diamond cannot be manufactured in any desirable shape, and thus is very difficult to handle and insert, for example, into a microcavity.

In this paper, we show that the use of single NV color center in diamond nanocrystals (typical size 50 nm) is a very convenient solution to these problems. The subwavelength size of the nanocrystals renders refraction irrelevant. One can simply think of the nanocrystal as a point source emitting light in air. Furthermore, the small volume of diamond excited by the pump light reduces the emitted background light. Also, diamond nanocrystals can be easily handled in order to be inserted in a cavity or to be deposited on a fiber tip [23]. In addition NV centers in diamond nanocrystals preserve all the important features of NV centers in bulk diamond. In particular, we have checked that the fluorescence spectrum of NV centers in

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nanocrystals at room temperature is the same as in bulk. By investigating the autocorrelation function under continuous wave (CW) and pulsed excitation, we demonstrate the possibility to use NV centers in diamond nanocrystals as a room temperature stable single-photon source.

2 Experimental set-up

The color center used in our experiments is the NV defect center in synthetic Ib diamond, with a zero phonon line at a wavelength of 637 nm [18]. The defect consists in a substitutional nitrogen and a vacancy in an adjacent site. A simplified level structure is a four-level scheme with fast non radiative decays within the two upper states and within the two lower states. This amounts to an incoherent two-level system. The lifetime of the excited state in the bulk is $\tau_b = 11.6$ ns [24].

NV centers are artificially created in synthetic MDA diamond powder from de Beers. Nitrogen is naturally present in diamond. Vacancies are created by irradiation with 1.5 MeV electrons at a dose of $3 \times 10^{17} e^-/\text{cm}^2$. Subsequent annealing in vacuum at 850 °C during 2 hours leads to the formation of NV centers [18]. The nanocrystals are dispersed by sonification in a solution of polymer (polyvinylpyrrolidone at 1 weight% in propanol). This allows the disaggregation of the particles and their stabilization in a colloidal state. Centrifugation at 11 000 rpm for 30 min allows us to select nanocrystal sizes of $d_0 = 90 \pm 30$ nm (measured by dynamical light scattering). The average number of NV centers in a nanocrystal has been evaluated to 8 (see below). Nanocrystals containing a single NV center should therefore have a size around $d_0/2 = 45$ nm, which lies in the lower wing of the size distribution. The nanocrystal solution is then spin coated at 3000 rpm on thin fused silica substrates. Evaporation of the solvent leaves a 30 nm thick film of polymer with the nanocrystals well dispersed on the surface. Their density was estimated to be around $0.02 \mu\text{m}^{-2}$. In most experiments we look at the centers from the other side of the plate, which is in contact with the oil of an immersion microscope lens (Nachet 004279, $NA = 1.3$).

The experimental setup (Fig. 1), based on a confocal microscope, has been described in detail elsewhere [19, 20]. The pump laser (CW or pulsed) is focused with an immersion oil, high numerical aperture objective ($NA = 1.3$), onto a diffraction limited spot (≈ 400 nm FWHM). The fluorescence light is collected by the same objective and after proper frequency and spatial filtering, it can either be sent on a spectrometer, or to a Hanbury-Brown and Twiss set-up using two avalanche photodiodes (APD) from EG&G. Appropriate data processing allows us to obtain the histogram of the time separations between successive photons. A slow (8 s response time) x - y - z computerized servo-loop is used to compensate for any drifts. Bandpass filters allow detection from 630 to 800 nm. This spectral window matches the broad emission spectrum of a NV center [18].

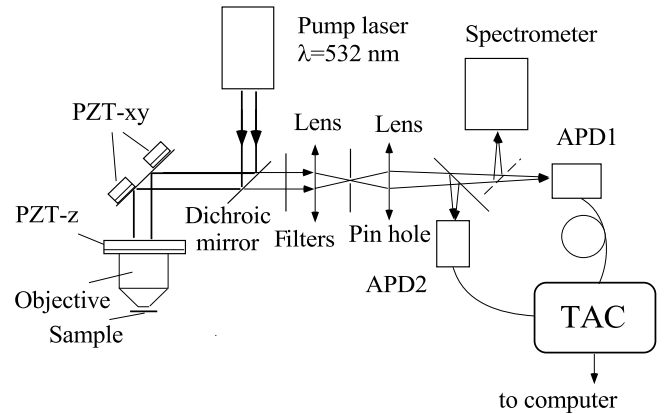


Fig. 1. Experimental set-up. The sample is excited by either a continuous or a pulsed frequency doubled YAG. Its fluorescence is collected using a confocal microscope set-up. The intensity correlations are measured using two avalanche photodiodes on each side of a 50/50 beam splitter, a time to amplitude converter and a multichannel analyzer.

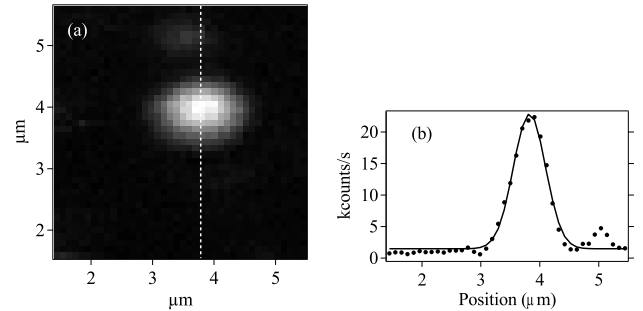


Fig. 2. (a) Confocal microscopy raster scan ($5 \times 5 \mu\text{m}^2$) of a diamond nanocrystal containing a single NV center. The count rate corresponds to one detector only. The size of a pixel is 100 nm and the integration time per pixel is 32 ms. The laser intensity impinging on the sample is 2.7 mW. In (b) a linescan along the dotted line of (a) is displayed, together with a Gaussian fit, which is used to evaluate the signal and background levels. Here we obtain $S/B = 20$. Note that the fluorescence spot is slightly larger (500 nm) than the size of the excitation laser spot (400 nm) owing to saturation of the emitter.

3 Continuous wave excitation

At first, we investigate the fluorescence of single NV centers in nanocrystals under CW excitation with a frequency doubled YAG laser ($\lambda = 532$ nm). Figure 2a displays a 2D scan of a single NV center. From the line scan in Figure 2b we deduce a spatial resolution of 500 nm and a signal (S) to background (B) ratio of $S/B = 20$. The corresponding value in the bulk is $S/B = 8$ (see Fig. 3).

Figure 3 shows the saturation behavior of the fluorescence rate of NV centers in bulk and in nanocrystals with respect to pump power. The slightly decreasing rate at high pump power is due to a trapping metastable state [20]. The saturating count rate in a diamond nanocrystal ($N_s^{\text{nc}} = 4.4 \times 10^4 \text{ s}^{-1}$) is slightly lower than that in bulk diamond ($N_s^{\text{b}} = 6.4 \times 10^4 \text{ s}^{-1}$), but

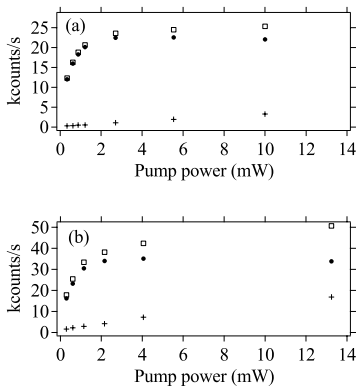


Fig. 3. Fluorescence rate of a NV center in a nanocrystal (a) and in bulk diamond (b) as a function of the pump power. The count rate corresponds to one detector only. The crosses, empty squares, and black circles represent the background B , the total count rate $T = S+B$, and the signal from the center $S = T-B$, respectively. The data for the nanocrystal corresponds to the same center as that shown in Figure 2.

one has to take into account the longer lifetime of a NV center in a nanocrystal (see at the end of this section). The number of photons detected in a lifetime is $\tau_{nc}N_s^{nc} = 11 \times 10^{-4}$ in the nanocrystal (lifetime $\tau_{nc} = 25$ ns) and $\tau_b N_s^b = 7.4 \times 10^{-4}$ in bulk diamond (lifetime $\tau_b = 11.6$ ns). This means that the geometrical collection efficiency for nanocrystals is increased by 50%.

It can also be seen in Figure 3 that the contribution of background next to the nanocrystal is greatly reduced. The background coming from the diamond nanocrystal itself is reduced mainly because the excited volume of diamond is smaller.

The evaluated overall detection efficiency is given by $\eta_T^i = \eta_{geo}^i \eta_{opt} \eta_{det}$, where $i = b, nc$ for the bulk or for a nanocrystal, respectively. The geometrical collection efficiencies for a dipole oriented orthogonally to the optical axis are $\eta_{geo}^b = 0.18$ and $\eta_{geo}^{nc} = 0.38$ (calculated). The optical transmission from the sample to the detectors is $\eta_{opt} = 0.25$ (measured), and the detector quantum efficiency is $\eta_{det} = 0.7$ (taken from the data sheet). In addition the NV center presents a metastable state in which the excitation can be shelved [18, 20, 21]. This leads to a reduction of the count rate by a factor equal to the saturated population $\sigma_2^\infty = 0.25 \pm 0.05$ of the excited state. This value has been inferred by fitting a saturation curve (*cf.* Fig. 3) and a set of autocorrelation functions (like Fig. 4) obtained for different pump powers [20]. This fit involves many parameters and gives only approximative results. For a nanocrystal, the saturated count rate should then be $S_{cw}^{nc} = \eta_T^{nc} \sigma_2^\infty / \tau_{nc} = 6.6 \times 10^5 \text{ s}^{-1}$, which is 15 times more than what we actually detected ($N_s = 4.4 \times 10^4 \text{ s}^{-1}$). This discrepancy exists also in bulk and its origin is still under investigation [22].

We have also studied the autocorrelation function of the fluorescence of single NV centers in diamond nanocrystals. The raw coincidences $c(\tau)$ (right axis) and autocorrelation function $g^{(2)}(\tau) = \langle I(t)I(t+\tau) \rangle / \langle I(t) \rangle^2$ (left axis) are represented in Figure 4.

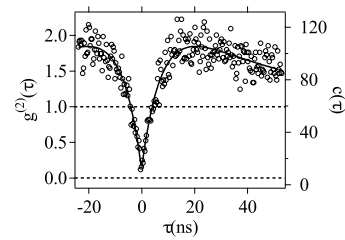


Fig. 4. Autocorrelation function $g^{(2)}(\tau)$ (left) and raw coincidence rate (right) for a NV center in a nanocrystal. The time bin is $w = 0.3$ ns, total integration time is 323 s and the laser intensity impinging on the sample is 2.7 mW. Count rates on each photodiode are $N_1 = 22\,500 \text{ s}^{-1}$ and $N_2 = 24\,500 \text{ s}^{-1}$. The actual number of coincidences is indicated on the right. The zero-time value of the uncorrected normalized correlation function given by equation (1) is $C_N(0) = 0.17$. The fit is performed with the model used in [20]. The data corresponds to the same center as that shown in Figure 2.

For evaluating the intensity correlation function $g^{(2)}(\tau)$ of the NV center, the raw correlation data $c(\tau)$ is normalized and corrected in the following way. The raw coincidence rate $c(\tau)$ counted during a time T within a time bin of width w is first normalized to that of a Poissonian source according to the formula

$$C_N^{cw}(\tau) = c(\tau) / (N_1 N_2 w T), \quad (1)$$

where $N_{1,2}$ are the count rates on each detector. The normalized coincidence rate $C_N^{cw}(\tau)$ is then corrected for the background light B , and we obtain

$$g^{(2)}(\tau) = [C_N^{cw}(\tau) - (1 - \rho^2)] / \rho^2, \quad (2)$$

where $\rho = S / (S+B)$ is related to the signal to background ratio, which is measured independently in each experimental run by measuring the count rate next to the nanocrystal (see Fig. 2b). This takes into account only the background coming from the fused silica and the polymer, and not the parasitic light emitted by the diamond nanocrystal itself. Note that we have checked experimentally that the background light has a Poissonian statistics.

It can be seen in Figure 4 that $g^{(2)}(0) = 0.13$, where the slight difference with zero is attributed to remaining background light emitted by the nanocrystal and electronic jitter of the avalanche photodiodes (300 ps). This almost vanishing value of $g^{(2)}(0)$ is the signature of the presence of a single emitter in the observed nanocrystal. In the case of the presence of p centers within a nanocrystal, the value of the zero-time antibunching is $1 - 1/p$. This is actually how we estimate the number of NV centers in a nanocrystal.

We have obtained a $\tau = 0$ normalized coincidence rate $C_N^{cw}(0) = 0.17$ at the fluorescence rate maximum (input power of 2.7 mW), where the best value in bulk diamond was 0.26 [20, 21]. As we shall see in the next section, this uncorrected normalized coincidence rate $C_N^{cw}(0)$ is the relevant parameter for characterizing a single photon source.

It should also be mentioned that $g^{(2)}(\tau)$ reaches values greater than unity for $|\tau| \geq 10$ ns. This bunching effect for longer time scale is due to the presence of the

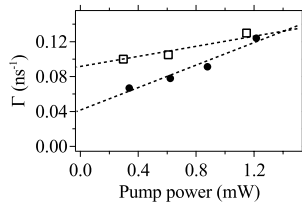


Fig. 5. Argument Γ of the exponential function fitting the antibunching traces obtained at different pump power. The extrapolation for vanishing pump power gives the lifetime. The black circles correspond to the data of Figure 2 and yield $\tau_{nc} = 25$ ns. The empty squares correspond to a NV center in bulk diamond ($\tau_b = 11.6$ ns). The slope for the nanocrystal is twice as large as that in bulk which is consistent with the lifetime increase, since the NV center in a nanocrystal can absorb twice as many photons during its lifetime.

trapping metastable state in which the system can be shelved [10, 25, 20, 26]. This effect can also be seen as blinking on a time scale of ≈ 50 ns. The time distribution of photons can be viewed as bursts of photons of about 50 ns duration. In each burst the delay between successive photons is always larger than 5 ns (antibunching).

In a low pump regime, the central dip in the antibunching traces can be fitted by an exponential function with the argument $-|\Gamma|\tau$, where $\Gamma = \gamma + r$, with γ being the NV center spontaneous decay rate and r the pumping rate [20]. Such fits have been performed for different pumping powers. The inverse lifetime $\gamma = 1/\tau_{nc}$ of an NV center in a nanocrystal can then be inferred by extrapolating the value of the time constant for vanishing pump power (Fig. 5). We deduce a lifetime for NV centers in bulk diamond of $\tau_b = 11.6 \pm 0.1$ ns [24] whereas the lifetime is found to be $\tau_{nc} = 25 \pm 4$ ns in diamond nanocrystals [27]. This value has been obtained by observing 10 different nanocrystals. A possible explanation for this lifetime increase is that the refractive index experienced by the emitted light is different in bulk diamond and nanocrystals. When working out the spontaneous emission rate from the Fermi's golden rule, it turns out that this rate is proportional to the refractive index n of the material in which the dipole is radiating.

In our case, the NV center in bulk diamond emits within a medium of index $n_d = 2.4$, whereas the center in a sub-wavelength nanocrystals emits as if it were in air for one half of the space, and in fused silica (refractive index $n_s = 1.45$) for the other half. The expected lifetime is then $\tau_{nc} = \tau_b[2n_d/(1 + n_s)] = 22.7$ ns in good agreement with the experimental values. A full description of lifetime changes due to refractive index is a controversial subject mainly because of local field correction issues [28–30]. However, our results tend to show that the local field experienced by the NV center in bulk and in nanocrystals is the same [27]. As mentioned earlier no substantial difference in the emission spectrum of NV centers in nanocrystals and in bulk has been found. This is a good indication that the observed lifetime change is mainly due to the modification of the refractive index of the medium in which the NV center is radiating.

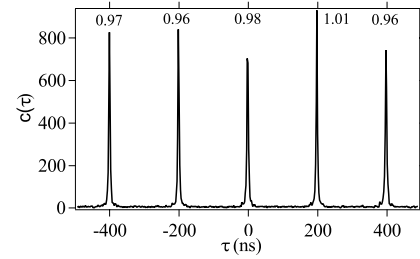


Fig. 6. Autocorrelation function from a fluorescing material (piece of white paper) excited by the pulsed laser. The emitted light has a Poissonian distribution. Pulse repetition period is 200 ns and the pulse width 1.2 ns. The count rates are $N_1 = 5011$ and $N_2 = 5343$ s $^{-1}$. Integration time is $T = 595$ s and the time bin is 2 ns. The area of each individual peak normalizes to unity.

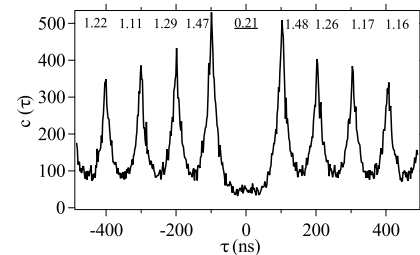


Fig. 7. Pulsed autocorrelation function of a single NV center. Pulse repetition period is 100 ns, pulse width 1.2 ns and excitation mean power 0.9 mW. Count rates are $N_1 = 10504$ s $^{-1}$ and $N_2 = 9995$ s $^{-1}$. Integration time is $T = 588$ s and the time bin is 2 ns. The coincidences between peaks do not go down to zero because of the overlapping of adjacent peaks. The number above each peak represents its normalized area.

4 Pulsed excitation

The pulsed excitation consists of a home build source along the lines of reference [31]. The output of a 100 mW continuous wave Nd:YAG laser ($\lambda = 1064$ nm) is coupled into a fast (3 GHz) integrated LiNbO₃ modulator (Alenia) which slices up pulses of 1 ns duration at a repetition rate of 10 MHz. The pulses are then amplified to 1 W mean power by an ytterbium fiber amplifier (Keopsys) and frequency doubled using a PPKTP crystal. In this way we obtain pulses at $\lambda = 532$ nm of energy 2.5 nJ.

We investigate the intensity autocorrelation function $g^{(2)}(\tau)$ of the fluorescence light of a single NV center in a nanocrystal under pulsed excitation. For a Poissonian source the probability of having a coincidence between two photons in the same pulse, or two photons coming from different pulses, is equal. Therefore the autocorrelation function for a pulsed Poissonian source exhibits peaks of same height separated by the repetition period (Fig. 6).

In Figure 7 is shown the intensity autocorrelation function of a single NV center under pulsed excitation. The excitation pulse duration is $d = 1.2$ ns and the repetition period is $\theta = 100$ ns. It can be seen that the peak around $\tau = 0$ is missing, which implies that the probability of having two photons in one pulse is strongly reduced. This gives rise to a highly sub-Poissonian light source. In order

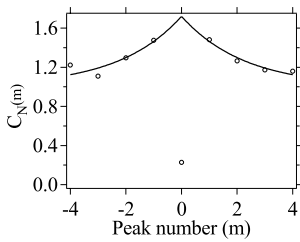


Fig. 8. Normalized peak area of Figure 7 as function of the peak number m . The experimental data is fitted with a function that assumes a random blinking of the NV center due to the trapping state.

to compare our single photon source to a pulsed Poissonian light source, one has to normalize the area $c(m)$ of peak number m to the area $N_1 N_2 \theta T$ of a peak corresponding to a pulsed Poissonian distribution with the same count rate, with T being the total acquisition time. Analogously to equation (1), the normalized area of each peak is given by

$$C_N(m) = c(m)/N_1 N_2 \theta T. \quad (3)$$

The determination of the area $c(m)$ is performed in the following way. The peaks are fitted by exponential decays with the same lifetime. We checked that the lifetime found from the fit is the same than that deduced from the CW excitation. This fitting procedure allows an accurate evaluation of the area $c(m)$ of peak m , in spite of the significant overlap between peaks. The normalized peak areas $C_N(m)$ are given by the numbers displayed above each peak in Figure 7. For a Poissonian pulsed light source $C_N(m) = 1$ for all m (see Fig. 6). For our single dipole in the most favorable case, in which the NV center is saturated but the zero time peak is as low as possible, we obtained $C_N(0) = 0.21$. Note that this value is slightly larger than $C_N^{cw}(0) = 0.17$. This is attributed to the finite duration ($d = 1.2$ ns) of the exciting pulses [7].

Let us recall that the probability p_2 of having two photons in a pulse is given by (assuming $p_2 \ll 1$)

$$p_2 = C_N(0) p_1^2/2 \quad (4)$$

where p_1 is the probability of having a single photon. Note that for Poissonian light $C_N(0) = 1$, and equation (4) with $C_N(0) = 1$ gives the photon probability distribution of an attenuated coherent pulse. The zero time normalized coincidence rate $C_N(0) = 0.21$ means that the rate of two photon pulses is nearly five times lower than for Poissonian light. Since our source has a single photon rate of 2×10^4 s⁻¹ at an excitation repetition rate of 10 MHz, its rate of two-photon pulses is only of 4 s⁻¹.

It can also be observed that the peaks $m \neq 0$ grow above unity. Just as in Figure 4, this bunching effect for non zero time scale comes from the existence of a metastable state [10,18,20,21,26]. In Figure 8 we have plotted the normalized area of the first peaks. The long time decay behavior can be described by a simple model assuming that the NV center gets randomly trapped in the metastable state. This results in random blinking of

the NV center. The normalized area of peak m is then given by [14]

$$C_N(m \neq 0) = 1 + \frac{T_{\text{off}}}{T_{\text{on}}} e^{-(1/T_{\text{off}} + 1/T_{\text{on}})|m|\theta}, \quad (5)$$

where T_{off} is the mean time during which the excitation is trapped in the metastable state and the emission is inhibited and T_{on} is the mean time during which the center is emitting. Fitting the normalized peak area (*cf.* Fig. 8) with equation (5) allows us to extract the values $T_{\text{on}} = 460$ ns, $T_{\text{off}} = 390$ ns. The saturated count rate should then be $S_p^{\text{nc}} = \eta_T^{\text{nc}} [T_{\text{on}}/(T_{\text{on}} + T_{\text{off}})]/\theta = 1.4 \times 10^5$ s⁻¹, while we detect only $N_s = 2 \times 10^4$ s⁻¹. This is the same discrepancy that what was observed for CW excitation [22]. Note that the factor $T_{\text{on}}/(T_{\text{on}} + T_{\text{off}}) = 0.54$ accounts for the shelving state and plays the same role as $\sigma_2^\infty = 0.25$ for CW excitation. Their different values are attributed to the fact that the shelving and deshelving rates depend on the excitation power [20] and are therefore different in CW and in pulsed regime.

5 Conclusion

In this paper we have demonstrated the possibility of using single NV centers in diamond nanocrystals as a room temperature solid state source for single photons. They present the advantages of being photostable and easy to manipulate. Furthermore the fabrication of the samples is easy and inexpensive. The single photon rate summed over both photodiodes is 2×10^4 s⁻¹ for an excitation repetition rate of 10 MHz. Our source exhibits a strong sub-Poissonian distribution. The two photon pulse rate is reduced by a factor of five compared to a Poissonian source and is equal to 4 s⁻¹. Improvements in the collection efficiency should be obtained by depositing the nanocrystals on a mirror or inserting them into a microcavity. Even though the repetition rate is low compared to what can be obtained with attenuated pulses using laser diodes, the reduction by a factor of 5 of the two photon pulses will allow a secure transmission over larger distances [5].

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